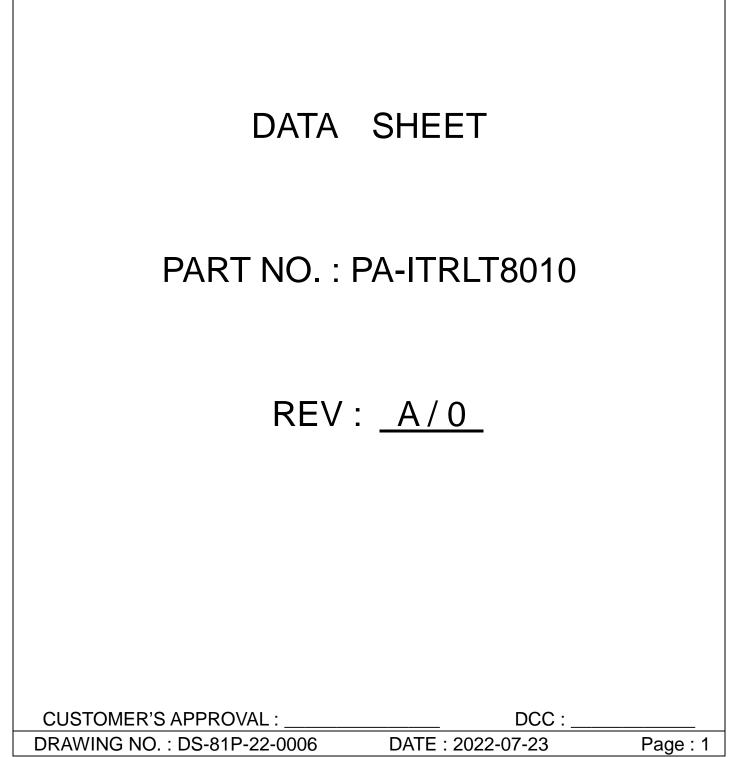


PARA LIGHT ELECTRONICS CO., LTD.

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LD-R/E020



PA-ITRLT8010

REV:A/0

Descriptions

The PA-ITRLT8010 consist of an infrared emitting diode and an NPN silicon

phototransistor, encased side-by-side on converging optical axis in a black thermoplastic housing,

The phototransistor receives radiation from the LED only .This is the normal situation. But when

an object is in between , phototransistor could not receives the radiation. For additional

component information , please refer to IR and PT.

Features

Fast response time High analytic Cut-off visible wavelength λp=940nm High sensitivity Pb free This product itself will remain within RoHS compliant version

Applications

Printers Switch Scanner Floppy disk driver Non-contact Switching For Direct Board

Device Selection Guide

Device No.	Chip Material	LENS COLOR
IR	GaAlAs	Water clear
РТ	Silicon	Water clear

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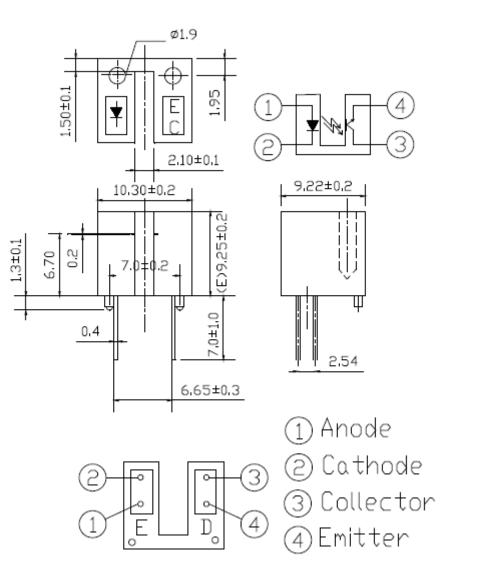
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PA-ITRLT8010

REV:A/0

Package Dimension



Note:

- 1.All dimensions are in millimeters.
- 2. Tolerances unless dimensions ±0.3mm.
- 3.Lead spacing is measured where the lead emerge from the package

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PA-ITRLT8010

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Absolute Maximum Ratings

	Parameter	Symbol	Ratings	Unit
Input	Power Dissipation at(or below) 25°C Free Air Temperature	Pd	75	mW
	Reverse Voltage	V _R	5	V
	Forward Current	$I_{\rm F}$	50	mA
	Peak Forward Current (*1) Pulse width $\leq 100 \mu$ s, Duty cycle=1%	I_{FP}	1	Α
Output	Collector Power Dissipation	Pc	75	mW
	Collector Current	IC	20	mA
	Collector-Emitter Voltage	B V _{CEO}	30	V
	Emitter-Collector Voltage	B V _{ECO}	5	V
Operating	ating Temperature Topr		-25~+85	°C
Storage Te	emperature	Tstg -40~+8		°C
	ering Temperature (*2) form body for 5 seconds)	Tsol 260		°C

(*1) tw=100 µsec. , T=10 msec. (*2) t=5 Sec

Electro-Optical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions
Input	Forward Voltage	V _F		1.2	1.5	V	I _F =20mA
	Reverse Current	IR			10	$\mu \mathbf{A}$	V _R =5V
	Peak Wavelength	λ _P		940		nm	I _F =20mA
	View Angle	201/2		40		Deg	I _F =20mA
Output	Dark C urrent	ICEO			100	nA	V _{CE} =20V,Ee=0mW/cm ²
	C-E Saturation Voltage	V _{CE} (sat)			0.4	v	I _C =2mA ,Ee=1mW/cm ²
Transfer Characteristics	Collect Current	I _C (ON)	0.9		15	mA	V _{CE} =5V
		I _C (OFF)			20	$\mu \mathbf{A}$	IF=20mA
	Rise time	tr		15		μ sec	V _{CE} =5V
	Fall time	t _f		15		$\mu \sec$	$I_C=1mA R_L=1K\Omega$
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PA-ITRLT8010

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Typical Electrical/Optical/Characteristics Curves for IR

Fig.1 Forward Current vs.

Ambient Temperature

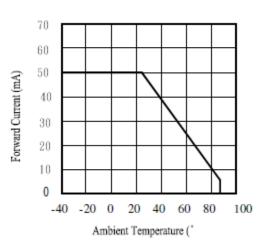
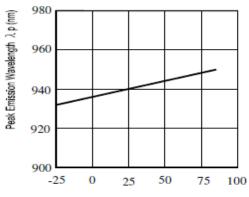


Fig.3 Peak Emission Wavelength vs. Ambient Temperature



Amblent Temperature (°C)

Fig.5 Forward Current vs

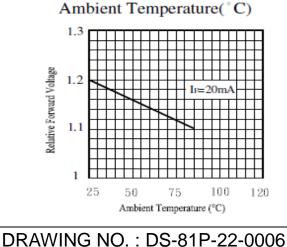
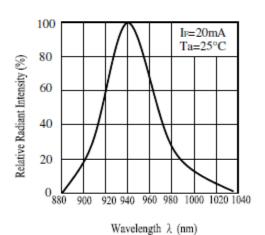


Fig.2 Spectral Distribution



Forward Current

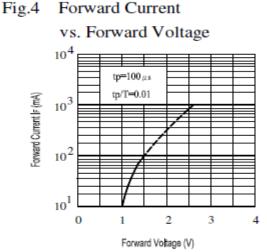
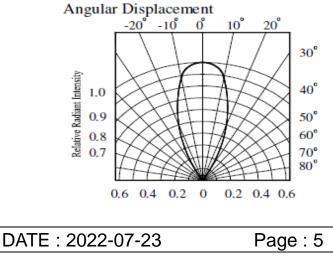


Fig.6 Relative Radiant Intensity vs.



PARA ight

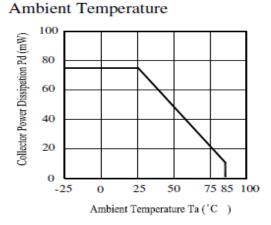
INFRARED REMOTE CONTROL RECEIVER MODULE

PA-ITRLT8010

REV:A/0

Typical Electrical/Optical/Characteristics Curves for PT

Fig.1Collector Power Dissipation vs.





Ambient Temperature

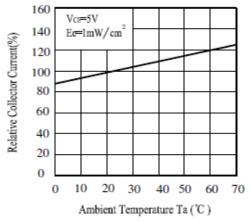


Fig.5 Collector Dark Current vs.

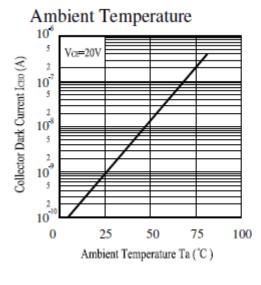


Fig.2 Spectral Sensitivity

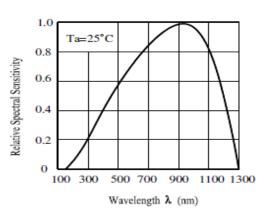


Fig.4 Collector Current vs.

Irradiance

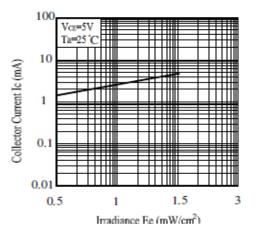
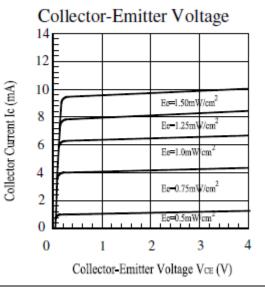


Fig.6 Collector Current vs.



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REV:A/0

Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

NO.	Item	Test Condition		Test Hours⁄ Cycle	Sample Size	Failure Judgement Criteria	Ac/R e
1	Solder Heat	TEMP : 260℃	±5℃	10 sec	22 PCs		0/1
2	Temperature Cycle	H:+100℃ ↓ L:-40℃	15 min 5 min 15 min	300 cycle	22 PCs	Ee \leq L×0.8 V _F \leq U	0/1
3	Thermal Shock	H:+100℃ ↓ L:-10℃	5 min 10 sec 5 min	300 cycle	22 PCs	U:Upper specification limit L:the initial test value	0/1
4	High Temperature Storage	TEMP. : +100°C		1000 hrs	22 PCs		0/1
5	Low Temperature Storage	TEMP. : -40°C		1000 hrs	22 PCs		0/1
6	DC Operating Life	V _{CE} =5V I _F =20mA		1000 hrs	22 PCs		0/1
7	High Temperature / High Humidity	85℃ / 85% R.H.		1000 hrs	22 PCs		0/1

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REV:A/0

Notes

- 1. Above specification may be changed without notice. WE will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instruction for using outlined in these specification sheets. Para light assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

3. These specification sheets include materials protected under copyright of corporation.Please don't reproduce or cause anyone to reproduce them without Para light's consent.